Absolute Maximum Ratings

	LF155A/6A/7A	LF155/6/7	LF355B/6B/7B LF255/6/7 LF355B/6B/7B	LF355A/6A/7A LF355/6/7
Supply Voltage	±22V	±22V	±22V	±18V
Power Dissipation (P_d at 25°C) and Thermal Resistance (θ_{jA}) (Note 1)				
T_{jMAX}				
(H and J Package)	150°C	150°C	115°C	115°C
(N Package)			100°C	100°C
(H Package) P_d	670 mW	670 mW	570 mW	570 mW
θ_{jA}	150°C/W	150°C/W	150°C/W	150°C/W
(J Package) P_d	670 mW	670 mW	570 mW	570 mW
θ_{jA}	140°C/W	140°C/W	140°C/W	140°C/W
(N Package) P_d			500 mW	500 mW
θ_{jA}			155°C/W	155°C/W
Differential Input Voltage	±40V	±40V	±40V	±30V
Input Voltage Range (Note 2)	±20V	±20V	±20V	±16V
Output Short Circuit Duration	Continuous	Continuous	Continuous	Continuous
Storage Temperature Range	−65°C to +150°C	−65°C to +150°C	−65°C to +150°C	−65°C to +150°C
Lead Temperature (Soldering, 10 seconds)	300°C	300°C	300°C	300°C

DC Electrical Characteristics (Note 3)

SYMBOL	PARAMETER	CONDITIONS	LF155A/6A/7A			LF355A/6A/7A			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	$R_S = 50\Omega$, $T_A = 25°C$		1	2		1	2	mV
		Over Temperature			2.5			2.3	mV
$\Delta V_{OS}/\Delta T$	Average TC of Input Offset Voltage	$R_S = 50\Omega$		3	5		3	5	µV/°C
$\Delta TC/\Delta V_{OS}$	Change in Average TC with V_{OS} Adjust	$R_S = 50\Omega$ (Note 4)		0.5			0.5		µV/°C per mV
I_{OS}	Input Offset Current	$T_J = 25°C$, (Notes 3, 5)		3	10		3	10	pA
		$T_J \leq T_{HIGH}$			10			1	nA
I_B	Input Bias Current	$T_J = 25°C$ (Notes 3, 5)		30	50		30	50	pA
		$T_J \leq T_{HIGH}$			25			5	nA
R_{IN}	Input Resistance	$T_J = 25°C$		10^{12}			10^{12}		Ω
A_{VOL}	Large Signal Voltage Gain	$V_S = \pm15V$, $T_A = 25°C$ $V_O = \pm10V$, $R_L = 2k$	50	200		50	200		V/mV
		Over Temperature	25			25			V/mV
V_O	Output Voltage Swing	$V_S = \pm15V$, $R_L = 10k$	±12	±13		±12	±13		V
		$V_S = \pm15V$, $R_L = 2k$	±10	±12		±10	±12		V
V_{CM}	Input Common Mode Voltage Range	$V_S = \pm15V$	±11	+15.1 −12		±11	+15.1 −12		V V
CMRR	Common-Mode Rejection Ratio		85	100		85	100		dB
PSRR	Supply Voltage Rejection Ratio	(Note 6)	85	100		85	100		dB

AC Electrical Characteristics $T_A = 25°C$, $V_S = \pm15V$

SYMBOL	PARAMETER	CONDITIONS	LF155A/355A			LF156A/356A			LF157A/357A			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew Rate	LF155A/6A, $A_V = 1$, LF157A, $A_V = 5$	3	5		10	12					V/µs
									40	50		V/µs
GBW	Gain Bandwidth Product			2.5		4	4.5		15	20		MHz
t_s	Settling Time to 0.01%	(Note 7)		4			1.5			1.5		µs
e_n	Equivalent Input Noise Voltage	$R_S = 100\Omega$										
		f = 100 Hz		25			15			15		$nV/\sqrt{Hz}$
		f = 1000 Hz		25			12			12		$nV/\sqrt{Hz}$
i_n	Equivalent Input Noise Current	f = 100 Hz		0.01			0.01			0.01		$pA/\sqrt{Hz}$
		f = 1000 Hz		0.01			0.01			0.01		$pA/\sqrt{Hz}$
C_{IN}	Input Capacitance			3			3			3		pF

DC Electrical Characteristics (Note 3)

SYMBOL	PARAMETER	CONDITIONS	LF155/6/7			LF255/6/7 LF355B/68/7B			LF355/6/7			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	$R_S = 50\Omega$, $T_A = 25°C$		3	5		3	5		3	10	mV
		Over Temperature			7			6.5			13	mV
$\Delta V_{OS}/\Delta T$	Average TC of Input Offset Voltage	$R_S = 50\Omega$		5			5			5		$\mu V/°C$
$\Delta TC/\Delta V_{OS}$	Change in Average TC with V_{OS} Adjust	$R_S = 50\Omega$, (Note 4)		0.5			0.5			0.5		$\mu V/°C$ per mV
I_{OS}	Input Offset Current	$T_j = 25°C$, (Notes 3, 5)		3	20		3	20		3	50	pA
		$T_j \leq T_{HIGH}$			20			1			2	nA
I_B	Input Bias Current	$T_J = 25°C$, (Notes 3, 5)		30	100		30	100		30	200	pA
		$T_J \leq T_{HIGH}$			50			5			8	nA
R_{IN}	Input Resistance	$T_J = 25°C$		10^{12}			10^{12}			10^{12}		Ω
A_{VOL}	Large Signal Voltage Gain	$V_S = \pm15V$, $T_A = 25°C$ $V_O = \pm10V$, $R_L = 2k$	50	200		50	200		25	200		V/mV
		Over Temperature	25			25			15			V/mV
V_O	Output Voltage Swing	$V_S = \pm15V$, $R_L = 10k$	±12	±13		±12	±13		±12	±13		V
		$V_S = \pm15V$, $R_L = 2k$	±10	±12		±10	±12		±10	±12		V
V_{CM}	Input Common-Mode Voltage Range	$V_S = \pm15V$	±11	+15.1 −12		±11	+15.1 −12		±10	+15.1 −12		V V
CMRR	Common-Mode Rejection Ratio		85	100		85	100		80	100		dB
PSRR	Supply Voltage Rejection Ratio	(Note 6)	85	100		85	100		80	100		dB

DC Electrical Characteristics $T_A = 25°C$, $V_S = \pm15V$

PARAMETER	LF155A/155, LF255, LF355A/355B		LF355		LF156A/156, LF256/356B		LF356A/356		LF157A/157 LF257/357B		LF357A/357		UNITS
	TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
Supply Current	2	4	2	4	5	7	5	10	5	7	5	10	mA

AC Electrical Characteristics $T_A = 25°C$, $V_S = \pm15V$

SYMBOL	PARAMETER	CONDITIONS	LF155/255/ 355/355B	LF156/256, LF356B	LF156/256/ 356/356B	LF157/257, LF357B	LF157/257/ 357/357B	UNITS
			TYP	MIN	TYP	MIN	TYP	
SR	Slew Rate	LF155/6: $A_V = 1$, LF157: $A_V = 5$	5	7.5	12			V/μs
GBW	Gain Bandwidth Product		2.5		5	30	50 20	V/μs MHz
t_s	Settling Time to 0.01%	(Note 7)	4		1.5		1.5	μs
e_n	Equivalent Input Noise Voltage	$R_S = 100\Omega$ f = 100 Hz	26		15		15	$nV/\sqrt{Hz}$
		f = 1000 Hz	20		12		12	$nV/\sqrt{Hz}$
i_n	Equivalent Input Current Noise	f = 100 Hz	0.01		0.01		0.01	$pA/\sqrt{Hz}$
		f = 1000 Hz	0.01		0.01		0.01	$pA/\sqrt{Hz}$
C_{IN}	Input Capacitance		3		3		3	pF

Notes for Electrical Characteristics

Note 1: The maximum power dissipation for these devices must be derated at elevated temperatures and is dictated by T_{JMAX}, θ_{JA}, and the ambient temperature, T_A. The maximum available power dissipation at any temperature is $P_d = (T_{JMAX} - T_A)/\theta_{JA}$ or the 25°C P_{dMAX}, whichever is less.

Note 2: Unless otherwise specified the absolute maximum negative input voltage is equal to the negative power supply voltage.

Note 3: Unless otherwise stated, these test conditions apply:

	LF155A/6A/7A LF155/6/7	LF255/6/7	LF355A/6A/7A	LF355B/6B/7B	LF355/6/7
Supply Voltage, V_S	$\pm 15V \le V_S \le \pm 20V$	$\pm 15V \le V_S \le \pm 20V$	$\pm 15V \le V_S \le \pm 18V$	$\pm 15V \le V_S \pm 20V$	$V_S = \pm 15V$
T_A	$-55°C \le T_A \le +125°C$	$-25°C \le T_A \le +85°C$	$0°C \le T_A \le +70°C$	$0°C \le T_A \le +70°C$	$0°C \le T_A \le +70°C$
T_{HIGH}	+125°C	+85°C	+70°C	+70°C	+70°C

and V_{OS}, I_B and I_{OS} are measured at $V_{CM} = 0$.

Note 4: The Temperature Coefficient of the adjusted input offset voltage changes only a small amount (0.5μV/°C typically) for each mV of adjustment from its original unadjusted value. Common-mode rejection and open loop voltage gain are also unaffected by offset adjustment.

Note 5: The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature, T_J. Due to limited production test time, the input bias currents measured are correlated to junction temperature. In normal operation the junction temperature rises above the ambient temperature as a result of internal power dissipation, Pd. $T_J = T_A + \Theta_{JA} Pd$ where Θ_{JA} is the thermal resistance from junction to ambient. Use of a heat sink is recommended if input bias current is to be kept to a minimum.

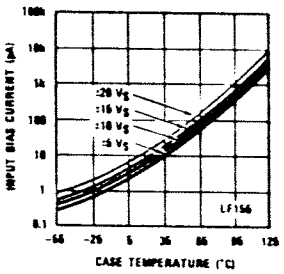
Note 6: Supply Voltage Rejection is measured for both supply magnitudes increasing or decreasing simultaneously, in accordance with common practice.

Note 7: Settling time is defined here, for a unity gain inverter connection using 2 kΩ resistors for the LF155/6. It is the time required for the error voltage (the voltage at the inverting input pin on the amplifier) to settle to within 0.01% of its final value from the time a 10V step input is applied to the inverter. For the LF157, $A_V = -5$, the feedback resistor from output to input is 2 kΩ and the output step is 10V (See Settling Time Test Circuit, page 9).

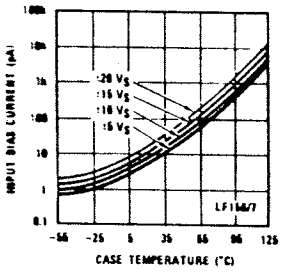
Typical DC Performance Characteristics

Curves are for LF155, LF156 and LF157 unless otherwise specified.

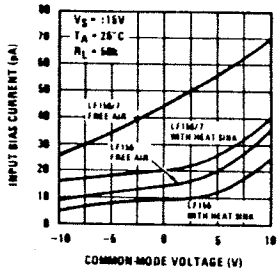
Input Bias Current



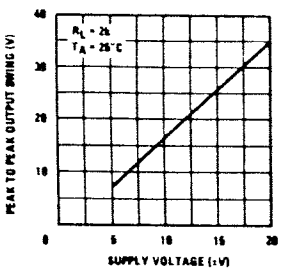
Input Bias Current



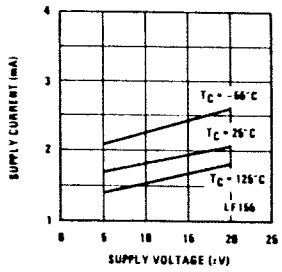
Input Bias Current



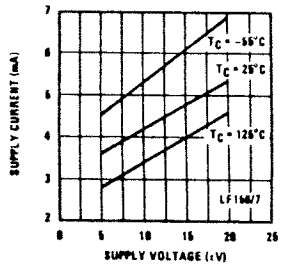
Voltage Swing



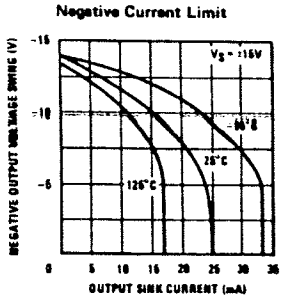
Supply Current



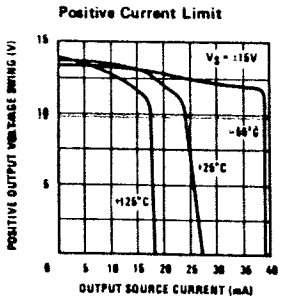
Supply Current



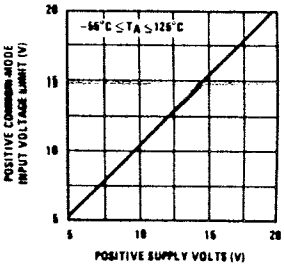
Negative Current Limit



Positive Current Limit

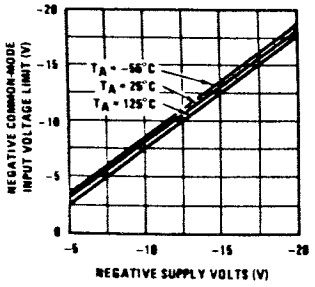


Positive Common-Mode Input Voltage Limit

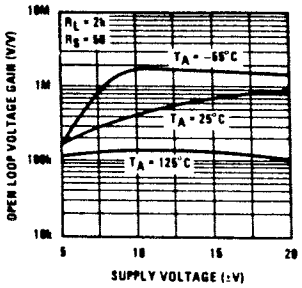


Typical DC Performance Characteristics (Continued)

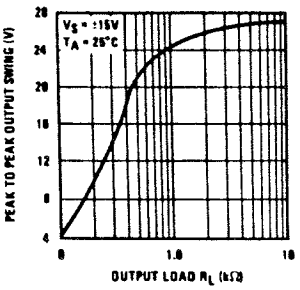
Negative Common-Mode Input Voltage Limit



Open Loop Voltage Gain

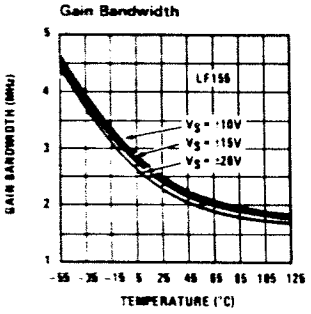


Output Voltage Swing

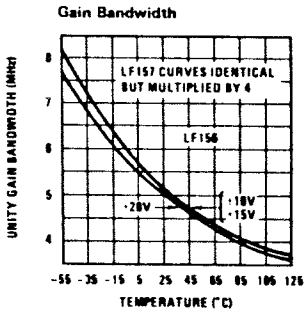


Typical AC Performance Characteristics

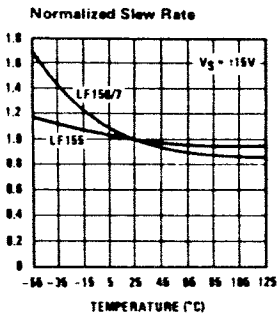
Gain Bandwidth



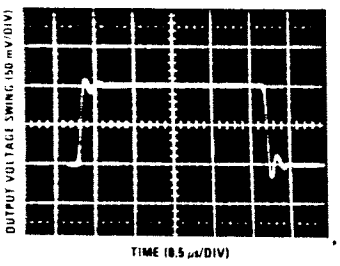
Gain Bandwidth



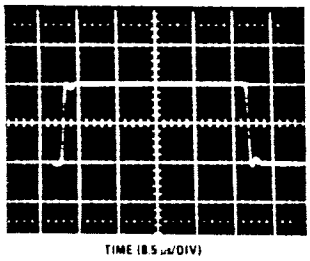
Normalized Slew Rate



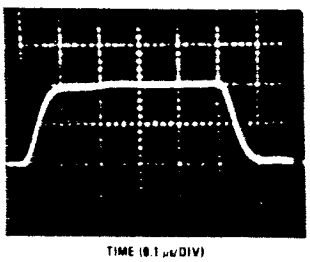
LF155 Small Signal Pulse Response, A_V = +1



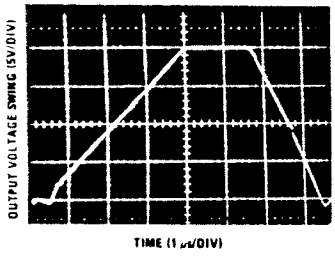
LF156 Small Signal Pulse Response, A_V = +1



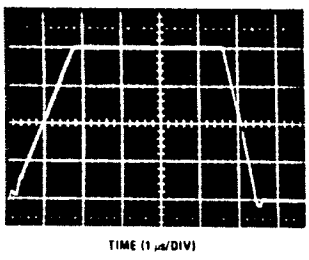
LF157 Small Signal Pulse Response, A_V = +5



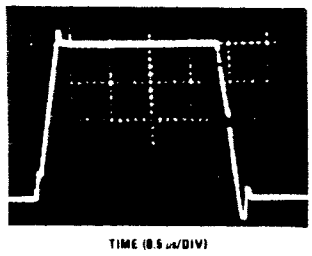
LF155 Large Signal Pulse Response, A_V = +1



LF156 Large Signal Pulse Response, A_V = +1

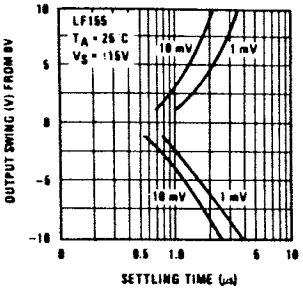


LF157 Large Signal Pulse Response, A_V = +5

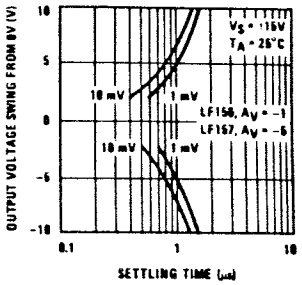


Typical AC Performance Characteristics (Continued)

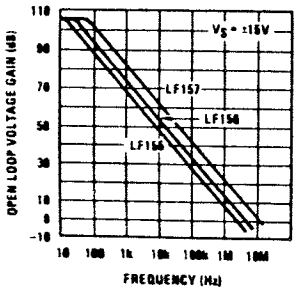
Inverter Settling Time



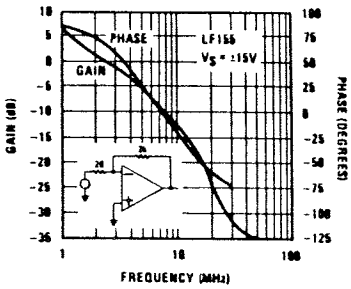
Inverter Settling Time



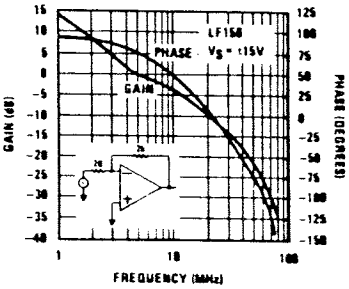
Open Loop Frequency Response



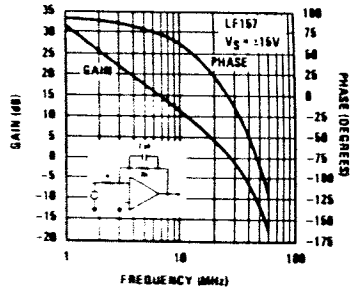
Bode Plot



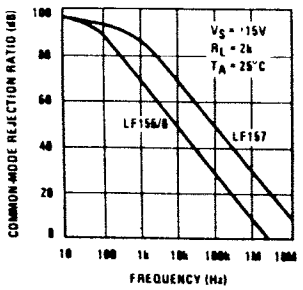
Bode Plot



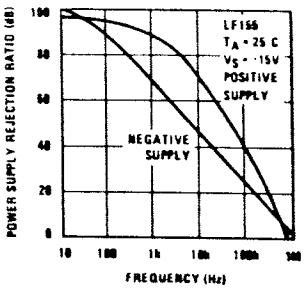
Bode Plot



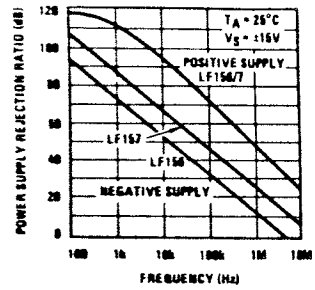
Common-Mode Rejection Ratio



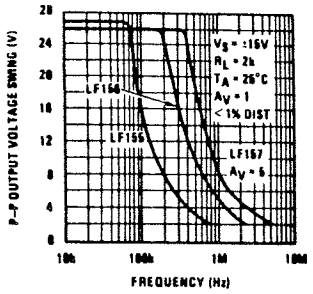
Power Supply Rejection Ratio



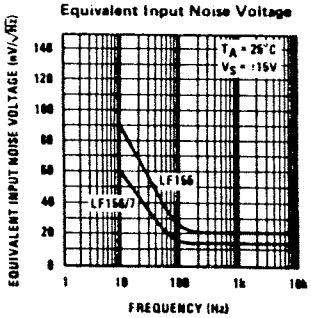
Power Supply Rejection Ratio



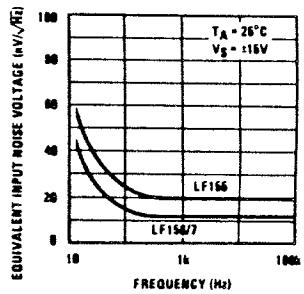
Undistorted Output Voltage Swing



Equivalent Input Noise Voltage

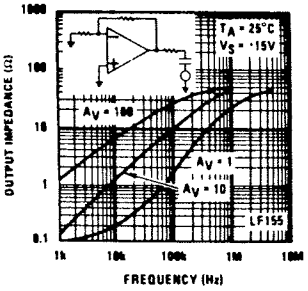


Equivalent Input Noise Voltage (Expanded Scale)

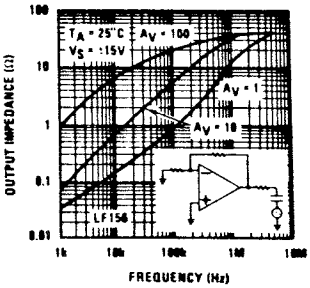


Typical AC Performance Characteristics (Continued)

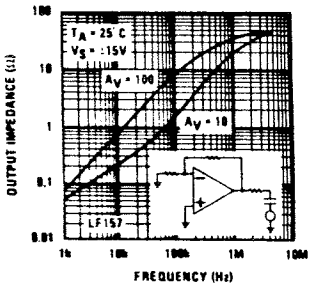
Output Impedance



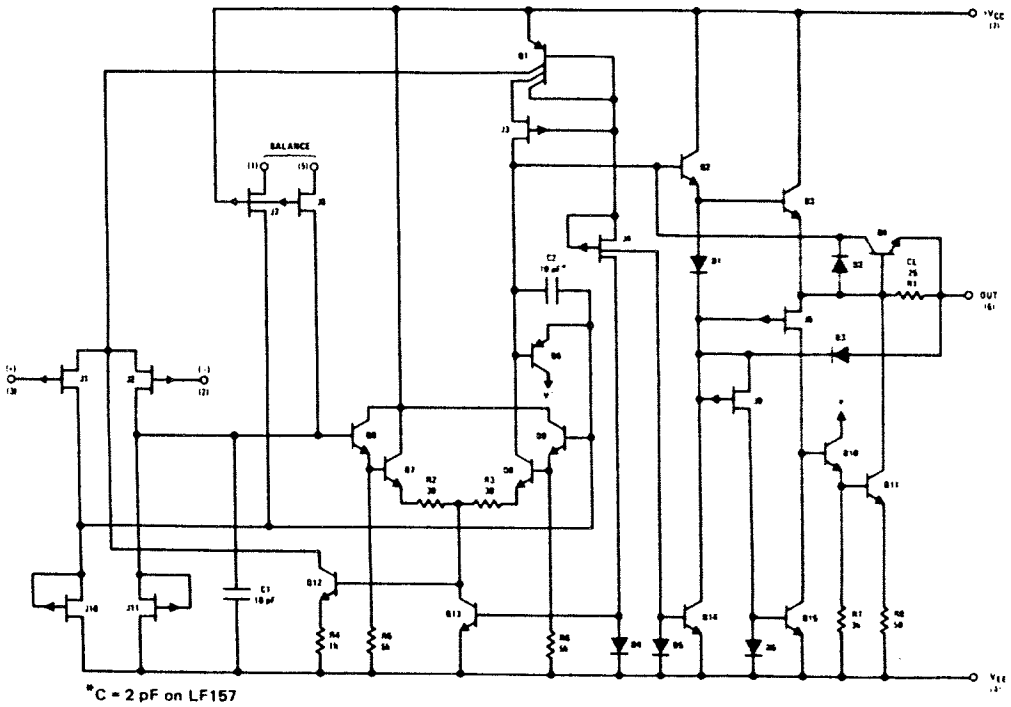
Output Impedance



Output Impedance



Detailed Schematic



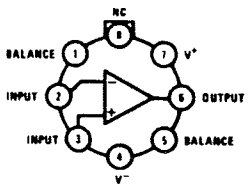
*C = 2 pF on LF157

Connection Diagrams (Top Views)

Metal Can Package

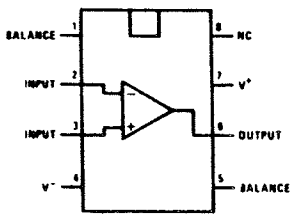
Order Number		
LF155AH	LF156AH	LF157AH
LF155H	LF156H	LF157H
LF255H	LF256H	LF257H
LF355AH	LF356AH	LF357AH
LF355H	LF356H	LF357H

See NS Package H08B



Note 4: Pin 4 connected to case.

Dual-In-Line Package



Order Number LF355N, LF356N or LF357N
See NS Package N08A

Order Number LF355J, LF356J or LF357J
See NS Package J08A

Application Hints

The LF155/6/7 series are op amps with JFET input devices. These JFETs have large reverse breakdown voltages from gate to source and drain eliminating the need for clamps across the inputs. Therefore large differential input voltages can easily be accomodated without a large increase in input current. The maximum differential input voltage is independent of the supply voltages. However, neither of the input voltages should be allowed to exceed the negative supply as this will cause large currents to flow which can result in a destroyed unit.

Exceeding the negative common-mode limit on either input will cause a reversal of the phase to the output and force the amplifier output to the corresponding high or low state. Exceeding the negative common-mode limit on both inputs will force the amplifier output to a high state. In neither case does a latch occur since raising the input back within the common-mode range again puts the input stage and thus the amplifier in a normal operating mode.

Exceeding the positive common-mode limit on a single input will not change the phase of the output however, if both inputs exceed the limit, the output of the amplifier will be forced to a high state.

These amplifiers will operate with the common-mode input voltage equal to the positive supply. In fact, the common-mode voltage can exceed the positive supply by approximately 100 mV independent of supply voltage and over the full operating temperature range. The positive supply can therefore be used as a reference on an input as, for example, in a supply current monitor and/or limiter.

Precautions should be taken to ensure that the power supply for the integrated circuit never becomes reversed in polarity or that the unit is not inadvertently installed backwards in a socket as an unlimited current surge through the resulting forward diode within the IC could cause fusing of the internal conductors and result in a destroyed unit.

Because these amplifiers are JFET rather than MOSFET input op amps they do not require special handling.

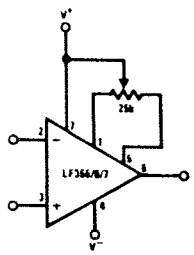
All of the bias currents in these amplifiers are set by FET current sources. The drain currents for the amplifiers are therefore essentially independent of supply voltage.

As with most amplifiers, care should be taken with lead dress, component placement and supply decoupling in order to ensure stability. For example, resistors from the output to an input should be placed with the body close to the input to minimize "pickup" and maximize the frequency of the feedback pole by minimizing the capacitance from the input to ground.

A feedback pole is created when the feedback around any amplifier is resistive. The parallel resistance and capacitance from the input of the device (usually the inverting input) to ac ground set the frequency of the pole. In many instances the frequency of this pole is much greater than the expected 3 dB frequency of the closed loop gain and consequently there is negligible effect on stability margin. However, if the feedback pole is less than approximately six times the expected 3 dB frequency a lead capacitor should be placed from the output to the input of the op amp. The value of the added capacitor should be such that the RC time constant of this capacitor and the resistance it parallels is greater than or equal to the original feedback pole time constant.

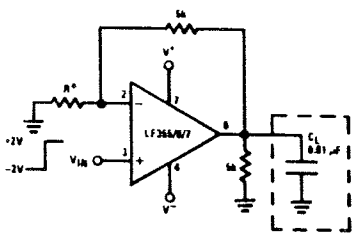
Typical Circuit Connections

V_{OS} Adjustment



- V_{OS} is adjusted with a 25k potentiometer
- The potentiometer wiper is connected to V^+
- For potentiometers with temperature coefficient of 100 ppm/°C or less the additional drift with adjust is ≈ 0.5 μV/°C/mV of adjustment
- Typical overall drift: 5 μV/°C ±(0.5 μV/°C/mV of adj.)

Driving Capacitive Loads



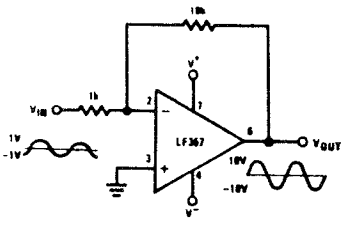
*LF155/6 R = 5k
LF157 R = 1.25k

Due to a unique output stage design, these amplifiers have the ability to drive large capacitive loads and still maintain stability. $C_{L(MAX)} \approx 0.01$ μF.

Overshoot ≤ 20%

Settling time (t_s) ≈ 5 μs

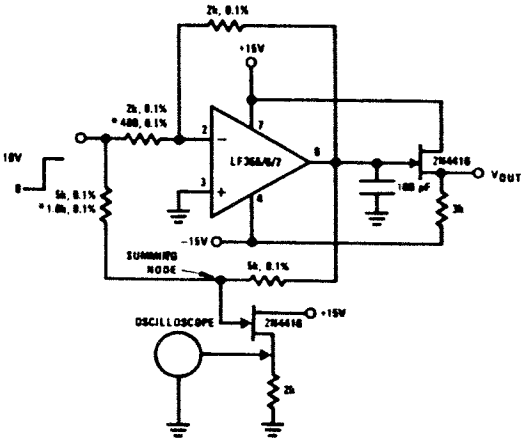
LF157. A Large Power BW Amplifier



For distortion ≤ 1% and a 20 Vp-p V_{OUT} swing, power bandwidth is: 500 kHz.

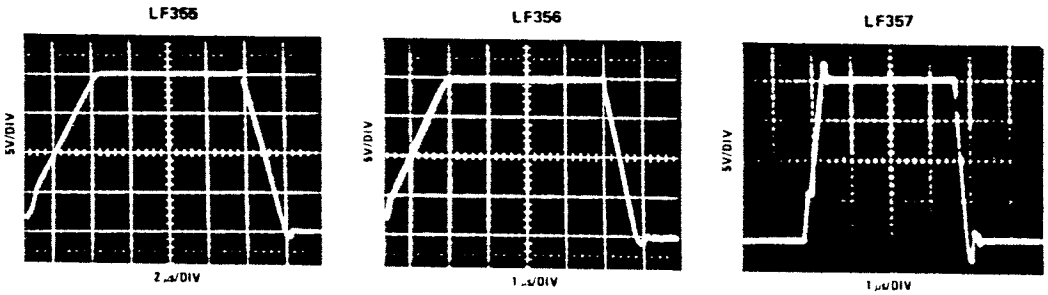
Typical Applications

Settling Time Test Circuit

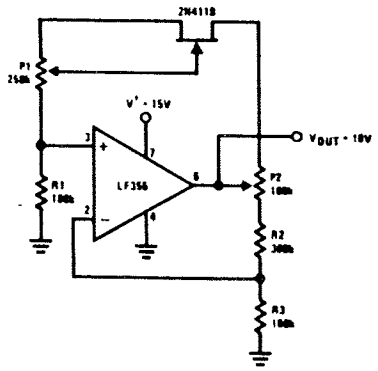


- Settling time is tested with the LF155/6 connected as unity gain inverter and LF157 connected for $A_V = -5$
- FET used to isolate the probe capacitance
- Output = 10V step
- $A_V = -5$ for LF157

Large Signal Inverter Output, V_{OUT} (from Settling Time Circuit)



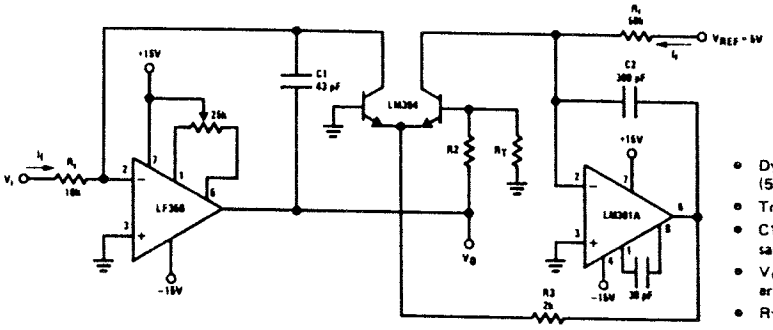
Low Drift Adjustable Voltage Reference



- $\Delta V_{OUT}/\Delta T = \pm 0.002\%/°C$
- All resistors and potentiometers should be wire-wound
- P1: drift adjust
- P2: V_{OUT} adjust
- Use LF155 for
  - Low I_B
  - Low drift
  - Low supply current

Typical Applications (Continued)

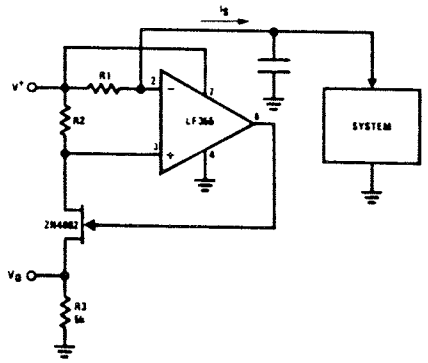
Fast Logarithmic Converter



- Dynamic range: 100 μA ≤ I_i ≤ 1 mA (5 decades), $|V_O|$ = 1V/decade
- Transient response: 3 μs for ΔI_i = 1 decade
- C1, C2, R2, R3: added dynamic compensation
- V_{OS} adjust the LF156 to minimize quiescent error
- R_T: Tel Labs type Q81 + 0.3%/°C

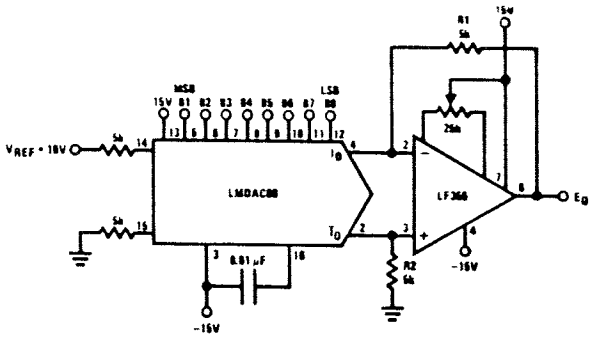
$$|V_{OUT}| = \left[1 + \frac{R2}{R_T}\right] \frac{kT}{q} \ln V_i \left[\frac{R_f}{V_{REF}\, R_i}\right] = \log V_i \frac{1}{R_i\, I_r}$$ R2 = 15.7k, R_T = 1k, 0.3%/°C (for temperature compensation)

Precision Current Monitor



- V_O = 5 R1/R2 (V/mA of I_S)
- R1, R2, R3 0.1% resistors
- Use LF155 for
  - Common-mode range to supply range
  - Low I_B
  - Low V_{OS}
  - Low supply current

8-Bit D/A Converter with Symmetrical Offset Binary Operation

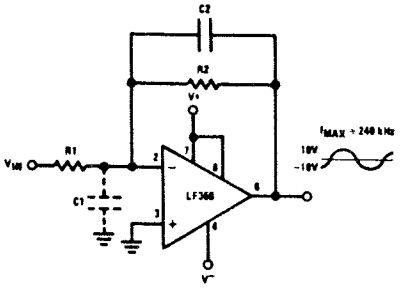


- R1, R2 should be matched within ±0.05%
- Full-scale response time: 3 μs

E_O	B1	B2	B3	B4	B5	B6	B7	B8	COMMENTS
+9.920	1	1	1	1	1	1	1	1	Positive Full-Scale
+0.040	1	0	0	0	0	0	0	0	(+) Zero-Scale
−0.040	0	1	1	1	1	1	1	1	(−) Zero-Scale
−9.920	0	0	0	0	0	0	0	0	Negative Full-Scale

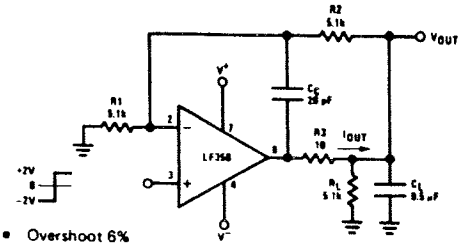
Typical Applications (Continued)

Wide BW Low Noise, Low Drift Amplifier



- Power BW: $f_{MAX} = \frac{S_r}{2\pi V_p} \cong 240$ kHz
- Parasitic input capacitance C1 ≅ (3 pF for LF155, LF156 and LF157 plus any additional layout capacitance) interacts with feedback elements and creates undesirable high frequency pole. To compensate add C2 such that: R2C2 ≅ R1C1.

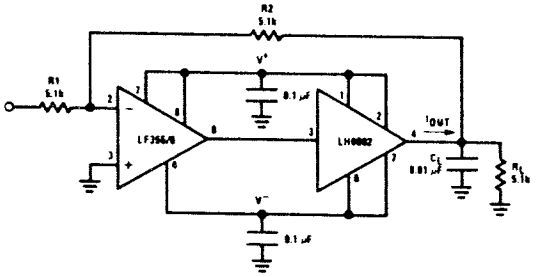
Isolating Large Capacitive Loads



- Overshoot 6%
- t_s 10 μs
- When driving large C_L, the V_{OUT} slew rate determined by C_L and $I_{OUT(MAX)}$:

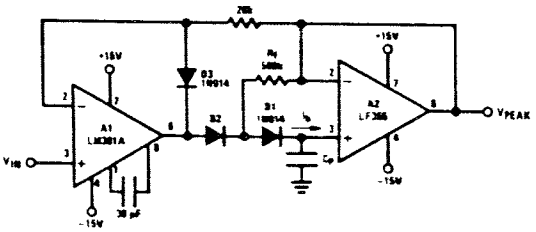
$$\frac{\Delta V_{OUT}}{\Delta T} = \frac{I_{OUT}}{C_L} \cong \frac{0.02}{0.5} \text{ V/μs} = 0.04 \text{ V/μs (with } C_L \text{ shown)}$$

Boosting the LF156 with a Current Amplifier



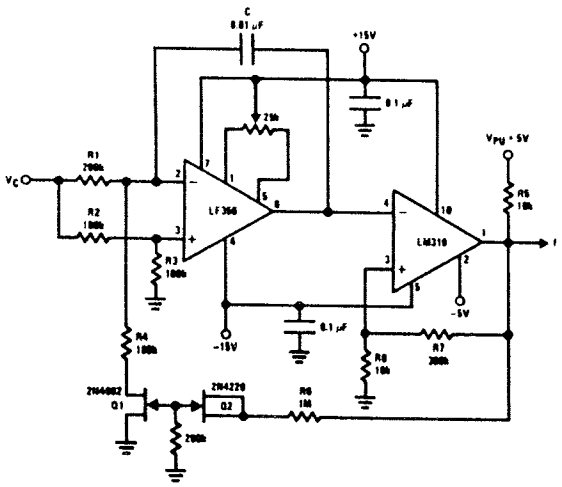
- $I_{OUT(MAX)} \cong 150$ mA (will drive $R_L \geq 100\Omega$)
- $\frac{\Delta V_{OUT}}{\Delta T} = \frac{0.15}{10^{-2}}$ V/μs (with C_L shown)
- No additional phase shift added by the current amplifier

Low Drift Peak Detector



- By adding D1 and R_f, $V_{D1} = 0$ during hold mode. Leakage of D2 provided by feedback path through R_f.
- Leakage of circuit is essentially I_b (LF155, LF156) plus capacitor leakage of C_p.
- Diode D3 clamps V_{OUT} (A1) to $V_{IN} - V_{D3}$ to improve speed and to limit reverse bias of D2.
- Maximum input frequency should be $<< 1/2\pi R_f C_{D2}$ where C_{D2} is the shunt capacitance of D2.

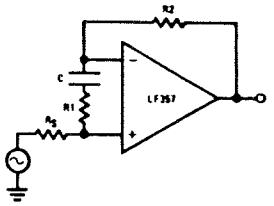
3 Decades VCO



$$f = \frac{V_C (R8+R7)}{(8\ V_{PU}\ R8\ R1|C} \quad , 0 \leq V_C \leq 30V,\ 10\text{ Hz} \leq f \leq 10\text{ kHz}$$

R1, R4 matched. Linearity 0.1% over 2 decades.

Non-Inverting Unity Gain Operation for LF157



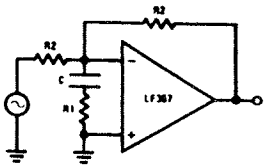
$$R1C \geq \frac{1}{(2\pi)\ (5\text{ MHz})}$$

$$R1 = \frac{R2 + R_S}{4}$$

$A_{V(DC)} = 1$

$f_{-3\,dB} \cong 5$ MHz

Inverting Unity Gain for LF157



$$R1C \geq \frac{1}{(2\pi)\ (5\text{ MHz})}$$

$$R1 = \frac{R2}{4}$$

$A_{V(DC)} = -1$

$f_{-3\,dB} \cong 5$ MHz